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July 2014

FDFMA2P853

Integrated P-Channel PowerTrench® MOSFET and Schottky Diode

General Description

This device is designed specifically as a single package solution for the battery charge switch in cellular handset and other ultra-portable applications. It features a MOSFET with low on-state resistance and an independently connected low forward voltage schottky diode for minimum conduction losses.

The MicroFET 2x2 package offers exceptional thermal performance for it's physlicize and is well suited to linear mode applications.

Features

MOSFET:

 \blacksquare -3.0 A, -20V. $R_{DS(ON)}$ = 120 $m\Omega$ @ V_{GS} = -4.5 V

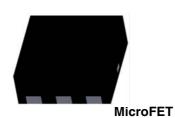
 $R_{DS(ON)} = 160 \text{ m}\Omega$ @ $V_{GS} = -2.5 \text{ V}$

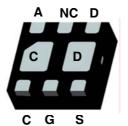
 $R_{DS(ON)} = 240 \text{ m}\Omega$ @ $V_{GS} = -1.8 \text{ V}$

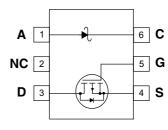
Schottky:

V_F < 0.46 V @ 500 mA

- Low Profile 0.8 mm maximun in the new package MicroFET 2x2 mm
- RoHS Compliant







Absolute Maximum Ratings T_A = 25°C unless otherwise noted

Symbol	Parameter	Ratings	Units	
V_{DSS}	MOSFET Drain-Source Voltage		-20	V
V_{GSS}	MOSFET Gate-Source Voltage		±8	V
	Drain Current -Continuous	(Note 1a)	-3.0	Α
ID	-Pulsed		-6	^
V_{RRM}	Schottky Repetitive Peak Reverse voltage		30	V
Io	Schottky Average Forward Current (Note 1a)		1	Α
В	Power dissipation for Single Operation	(Note 1a)	1.4	w
P_{D}	Power dissipation for Single Operation	(Note 1b)	0.7	"
T _J , T _{STG}	Operating and Storage Junction Temperature Range		-55 to +150	°C

Thermal Characteristics

$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	(Note 1a)	86	
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	(Note 1b)	173	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	(Note 1c)	86	- C/VV
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	(Note 1d)	140	

Package Marking and Ordering Information

Device Marking	Device	Reel Size	Tape Width	Quantity
.853	FDFMA2P853	7inch	8mm	3000 units

Symbol	Parameter	Test Co	nditions	Min	Тур	Max	Units
Off Char	acteristics	1					•
BV _{DSS}	Drain-Source Breakdown Voltage	$V_{GS} = 0 V$, I_D	= –250 μA	-20			V
<u>∆BV_{DSS}</u>	Breakdown Voltage Temperature	$I_D = -250 \mu\text{A}, \text{Refe}$	erenced to 25°C		-12		mV/°C
ΔT _J	Coefficient				-12	<u> </u>	
I _{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = -16 \text{ V}, V_{G}$				-1	μA
I _{GSS}	Gate-Body Leakage	$V_{GS} = \pm 8 \text{ V}, V_{D}$	S = 0 V			±100	nA
On Char	acteristics (Note 2)						
$V_{GS(th)}$	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D}$	= –250 μΑ	-0.4	-0.7	-1.3	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate Threshold Voltage Temperature Coefficient	I _D = -250 μA, Refe			2		mV/°C
$R_{DS(on)}$	Static Drain–Source	$V_{GS} = -4.5 \text{ V}, I_{D}$			90	120	mΩ
	On–Resistance	$V_{GS} = -2.5 \text{ V}, I_{D} = 1.8 \text{ V}, I_{D} = 1.8 \text{ V}$			120 172	160 240	
		$V_{GS} = -1.8 \text{ V}, I_D = -4.5 \text{ V}, I_D = -4.5 \text{ V}$			112	160	
I _{D(on)}	On–State Drain Current	$V_{GS} = -4.5 \text{ V}, V_{D}$		-20			Α
9rs	Forward Transconductance	$V_{DS} = -5 \text{ V}, I_{D}$			7		S
	Characteristics	, 5		ı	ı		
C _{iss}	Input Capacitance	V _{DS} = -10 V, V _O	ss = 0 V		435		pF
Coss	Output Capacitance	f = 1.0 MHz			80		pF
C _{rss}	Reverse Transfer Capacitance				45		pF
Switchin	g Characteristics (Note 2)	•					
t _{d(on)}	Turn-On Delay Time	V _{DD} = -10 V, I _D	= –1 A.		9	18	ns
t _r	Turn–On Rise Time	$V_{GS} = -4.5 \text{ V}, R_{GEN} = 6 \Omega$			11	19	ns
t _{d(off)}	Turn-Off Delay Time	1			15	27	ns
t _f	Turn-Off Fall Time	1			6	12	ns
Qq	Total Gate Charge	$V_{DS} = -10 \text{ V}, I_{D} = -3.0 \text{ A}, \ V_{GS} = -4.5 \text{ V}$			4	6	nC
Q _{gs}	Gate–Source Charge				0.8		nC
Q _{ad}	Gate-Drain Charge				0.9		nC
	ource Diode Characteristics	and Maximum	Patings	<u> </u>	Į.	<u> </u>	
l _s	Maximum Continuous Drain–Source					-1.1	Α
V _{SD}	Drain–Source Diode Forward Voltage	V _{GS} = 0 V, I _S	= -1.1 A (Note 2)		-0.8	-1.2	V
t _{rr}	Diode Reverse Recovery Time	$I_F = -3.0 \text{ A},$			17		ns
Q _{rr}	Diode Reverse Recovery Charge	dI _F /dt = 100 A/μs			6		nC
Schottky	Diode Characteristics						
I _R	Reverse Leakage	V _R = 5 V	T _J = 25°C		9.9	50	μА
			T _J = 125°C		2.3	10	mA
I _R	Reverse Leakage	V _R = 20 V	T _J = 25°C		9.9	100	μΑ
			T _J = 85°C		0.3	1	mA
			T _J = 125°C		2.3	10	mA
V _F	Forward Voltage	I _F = 500mA	T _J = 25°C		0.4	0.46	V
			T _J = 125°C		0.3	0.35	
V _F	Forward Voltage	I _F = 1A	T _J = 25°C		0.5	0.55	V
			T _J = 125°C		0.49	0.54	

Electrical Characteristics T_A = 25°C unless otherwise noted

Notes

- 1. $R_{\theta,JA}$ is determined with the device mounted on a 1 in² oz. copper pad on a 1.5 x 1.5 in. board of FR-4 material. $R_{\theta,JC}$ is guaranteed by design while $R_{\theta,JA}$ is determined by the user's board design.
 - (a) MOSFET $R_{\theta JA}$ = 86°C/W when mounted on a 1 in² pad of 2 oz copper, 1.5" x 1.5" x 0.062" thick PCB
 - (b) MOSFET $R_{\theta JA}$ = 173°C/W when mounted on a minimum pad of 2 oz copper
 - (c) Schottky R $_{\theta JA}$ = 86°C/W when mounted on a 1 in 2 pad of 2 oz copper, 1.5" x 1.5" x 0.062" thick PCB
 - (d) Schottky $R_{\theta JA} = 140^{\circ}$ C/W when mounted on a minimum pad of 2 oz copper



a) 86°C/W when mounted on a 1in² pad of 2 oz copper



b) 173°C/W when mounted on a minimum pad of 2 oz copper



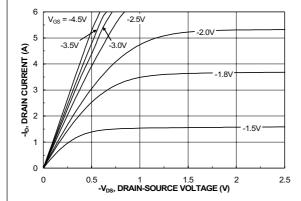
c) 86°C/W when mounted on a 1in² pad of 2 oz copper



Scale 1: 1 on letter size paper

2. Pulse Test: Pulse Width < $300\mu s$, Duty Cycle < 2.0%

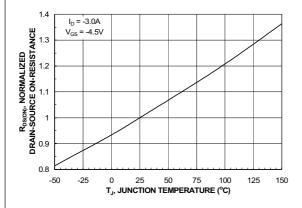
Typical Characteristics



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Figure 1. On-Region Characteristics

Figure 2. On-Resistance Variation with Drain Current and Gate Voltage



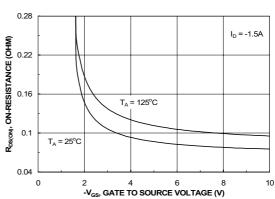
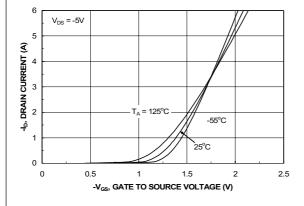


Figure 3. On-Resistance Variation with Temperature

Figure 4. On-Resistance Variation with Gate-to-Source Voltage



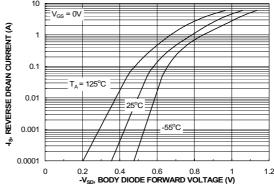
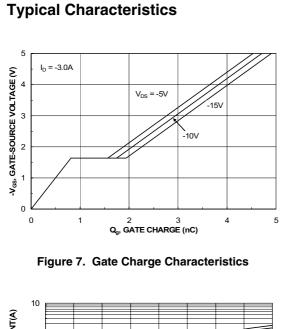


Figure 5. Transfer Characteristics

Figure 6. Body Diode Forward Voltage Variation with Source Current and Temperature



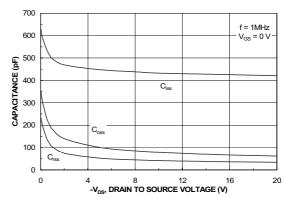
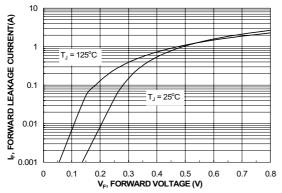


Figure 8. Capacitance Characteristics



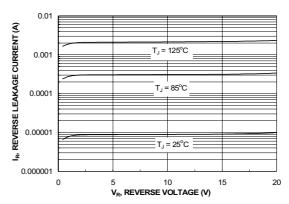


Figure 9. Schottky Diode Forward Voltage

Figure 10. Schottky Diode Reverse Current

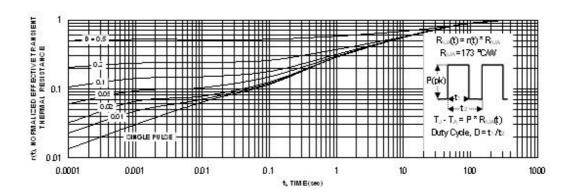
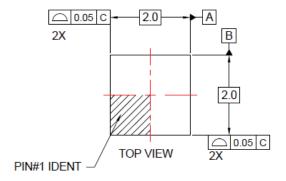
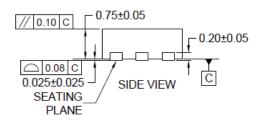


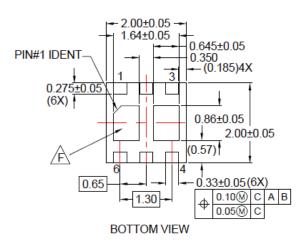
Figure 11. Transient Thermal Response Curve

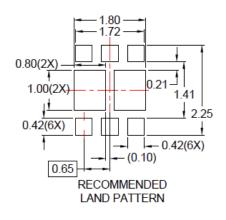
Thermal characterization performed using the conditions described in Note 1c. Transient thermal response will change depending on the circuit board design.

Dimensional Outline and Pad Layout









NOTES:

- A. CONFORM TO JADEC REGISTRATIONS MO-229, VARIATION VCCC, EXCEPT WHERE NOTED.
- B. DIMENSIONS ARE IN MILLIMETERS.
- C. DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 2009.
- LAND PATTERN RECOMMENDATION IS EXISTING INDUSTRY LAND PATTERN.
- E. DRAWING FILENAME: MKT-UMLP16Erev4
- F. NON-JEDEC DUAL DAP



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